

Electronic Supplementary Information

Three-dimensional hyperbranched TiO₂/ZnO heterostructured arrays for efficient quantum dot-sensitized solar cells

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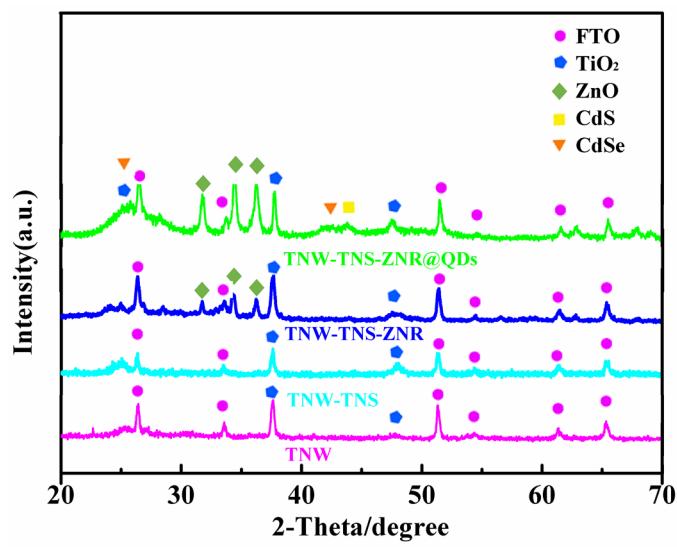


Figure S1 XRD patterns of TNW, TNW-TNS, TNW-TNS-ZNR and TNW-TNS-ZNR@QDs on FTO glass substrate.

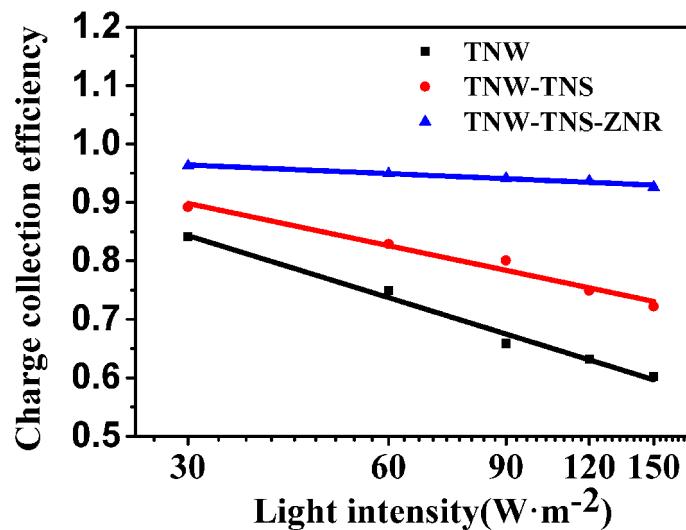


Figure S2 The charge-collection efficiency of QDSSCs based on TNW, TNW-TNS and TNW-TNS-ZNR arrays photoanodes.

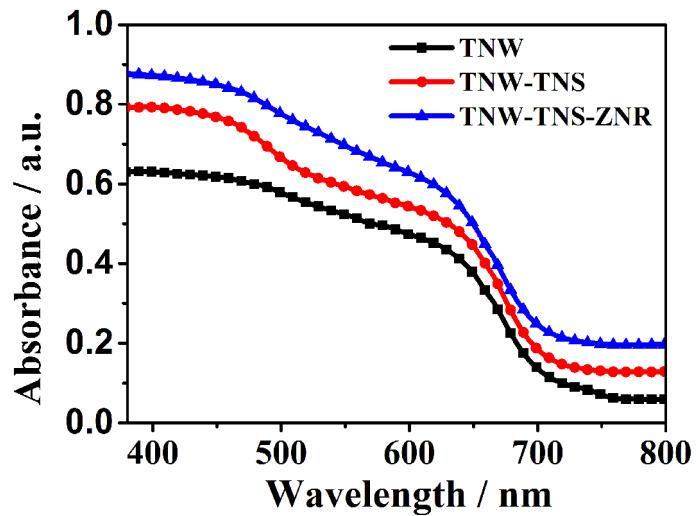


Figure S3 UV-vis absorption spectra of CdS/CdSe sensitized photoanodes based on TNW, TNW-TNS, TNW-TNS-ZNR arrays.

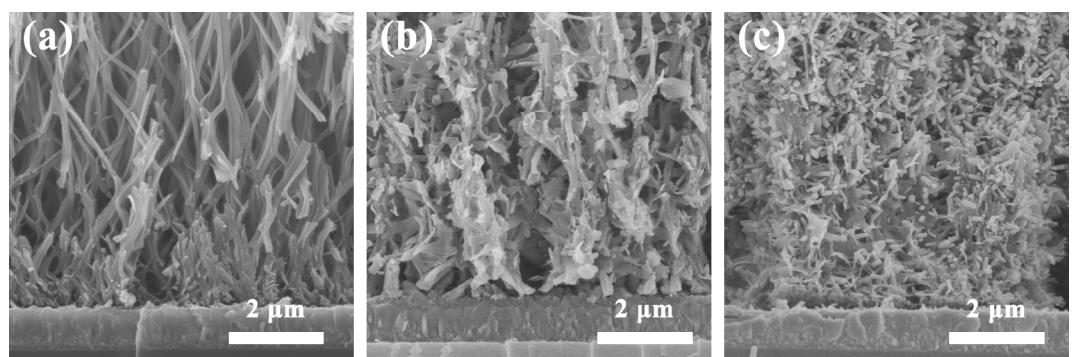


Figure S4 Zoom-in SEM images showing the connection features between the roots of (a) TNW, (b) TNW-TNS and (c) TNW-TNS-ZNR (c) arrays and FTO glass substrate.

Table S1 Detailed values of Resistance (R) and electron lifetime value (τ_r) from EIS spectra simulated by equivalent circuit as shown in Figure 4a.

QDSSCs	R_s	R_2 (ohm)	τ_r (s)
TNW	12.85	52.11	0.066
TNW-TNS	12.82	94.13	0.088
TNW-TNS-ZNR	12.01	103.9	0.096

Table S2 Detailed photovoltaic parameters of QDSSCs based on different arrays photoanodes and counter electrodes.

QDSSCs	J_{SC} /mA·cm ⁻²	V_{OC} /mV	η /%	FF
TNW	12.98	477	2.85	0.46
TNW-TNS	14.71	489	3.75	0.52
TNW-TNS-ZNR	15.95	505	4.25	0.53
TNW-TNS-ZNR with Cu ₂ S	19.19	517	5.38	0.54